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View Online at https://aerobasegroup.com/nsn/5961-01-179-5447 **Inclosure Material:** Metal **Overall Length:** 0.175 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.352 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-78 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 7.0 emitter to base voltage, static, collector open all transistor and 40.0 collector to base voltage/static/emitter open all transistor **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.75 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Lead surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

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